NSN 5961-00-458-1164

Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.190 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.219 inches
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
60.0 breakdown voltage, collector-to-emitter, base open all transistor
Power Rating Per Characteristic:
600.0 milliwatts small-signal input power, common-collector absolute all transistor
Transfer Ratio:
200.0 static forward current transfer ratio, common-emitter all transistor
Special Features:
All transistor junction pattern arrangement: pnp
Terminal Type And Quantity:
6 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0